Ordering number : ENN7124

N-Channel Silicon MOSFET





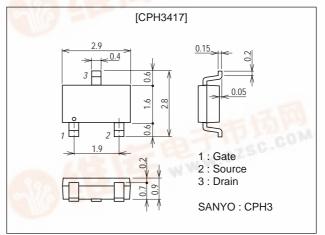
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 1.8V drive.

Package Dimensions

unit : mm 2152A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		1.8	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	7.2	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	0.9	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg	10. 44. 4	-55 to +125	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1A	1.9	2.8	W	S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =1A, V _{GS} =4V		160	210	mΩ
	RDS(on)2	I _D =0.5A, V _{GS} =2.5V		200	280	mΩ
	RDS(on)3	ID=0.1A, VGS=1.8V	10-14	280	390	mΩ

Marking: KS Continued on next page.

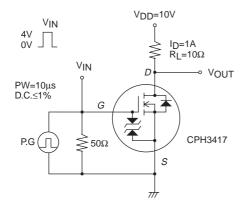
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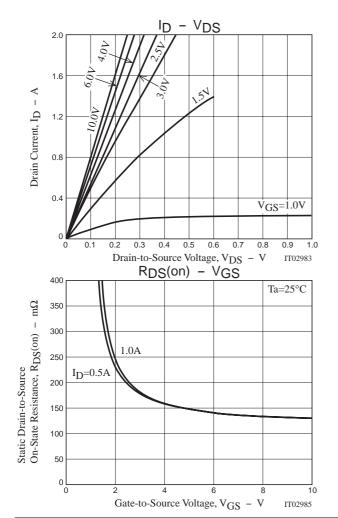
CPH3417

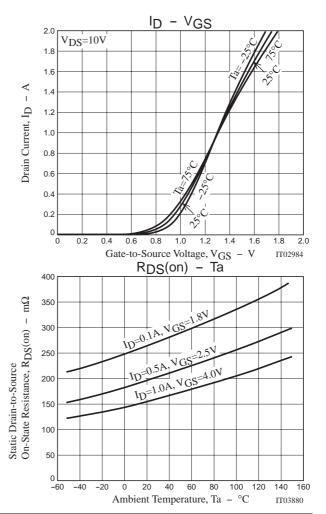
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Parameter	Symbol	Conditions	Ratings			Unit
i didiffetei			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		100		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		22		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		15		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		5.5		ns
Rise Time	t _r	See specified Test Circuit.		18		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		17		ns
Fall Time	tf	See specified Test Circuit.		8		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =1.8A		4.5		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =1.8A		0.4		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=10V, VGS=10V, ID=1.8A		0.4		nC
Diode Forward Voltage	V _{SD}	I _S =1.8A, V _{GS} =0		0.91	1.2	V

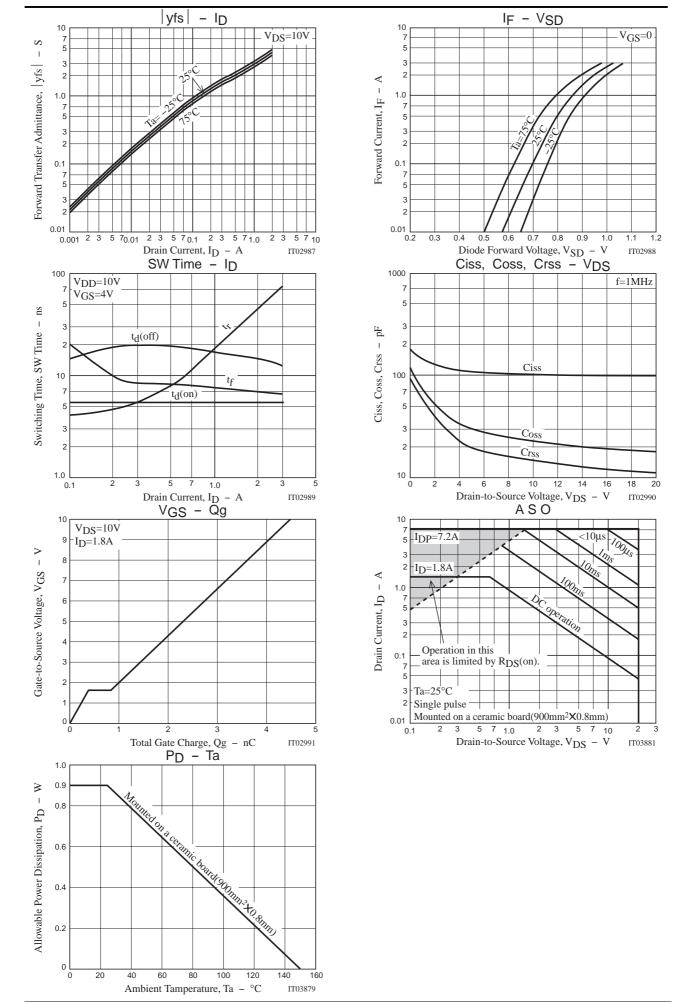
Switching Time Test Circuit







CPH3417



CPH3417

Note on usage: Since the CPH3417 is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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